



Features

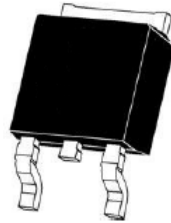
- Super high dense cell design for extremely low RDS(on)
- High power and current handing capability
- Lead free product is acquired

Application

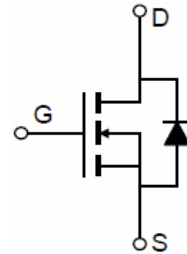
- Load Switch
- PWM Application
- Power management

Product Summary

BVDSS	20	V
RDS(on),Typ.@VGS=4.5V	20	mΩ
ID	20	A



TO-252-2L top view



Schematic diagram

Absolute Maximum Ratings (T_C=25°C unless otherwise noted)

Parameter	Symbol	Limit	Units
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	±12	V
Drain Current-Continuous	I _D	20	A
Drain Current-Pulsed ^a	I _{DM}	80	A
Maximum Power Dissipation @ T _C = 25°C - Derate above 25°C	P _D	32	W
		0.25	W/°C
Operating and Store Temperature Range	T _J , T _{stg}	-55 to 150	°C

Thermal Characteristics

Parameter	Symbol	Limit	Units
Thermal Resistance, Junction-to-Case	R _{θJC}	4	°C/W
Thermal Resistance, Junction-to-Ambient	R _{θJA}	50	°C/W

**Electrical Characteristics** $T_C = 25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS} = 0V, I_D = 250\mu A$	20			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20V, V_{GS} = 0V$			1	μA
Gate Body Leakage Current, Forward	I_{GSSF}	$V_{GS} = 12V, V_{DS} = 0V$			100	nA
Gate Body Leakage Current, Reverse	I_{GSSR}	$V_{GS} = -12V, V_{DS} = 0V$			-100	nA
On Characteristics^b						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS} = V_{DS}, I_D = 250\mu A$	0.4		1.0	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 4.5V, I_D = 8A$		20	42	$m\Omega$
		$V_{GS} = 2.5V, I_D = 6.6A$		25	75	$m\Omega$
Forward Transconductance	g_{FS}	$V_{DS} = 10V, I_D = 8A$		15		S
Dynamic Characteristics^c						
Input Capacitance	C_{iss}	$V_{DS} = 15V, V_{GS} = 0V, f = 1.0\text{ MHz}$		515		pF
Output Capacitance	C_{oss}			220		pF
Reverse Transfer Capacitance	C_{rss}			80		pF
Switching Characteristics^c						
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 10V, I_D = 1A, V_{GS} = 4.5V, R_{GEN} = 6\Omega$		19		ns
Turn-On Rise Time	t_r			13		ns
Turn-Off Delay Time	$t_{d(off)}$			48		ns
Turn-Off Fall Time	t_f			9		ns
Total Gate Charge	Q_g	$V_{DS} = 10V, I_D = 8A, V_{GS} = 4.5V$		10		nC
Gate-Source Charge	Q_{gs}			3		nC
Gate-Drain Charge	Q_{gd}			2		nC
Drain-Source Diode Characteristics and Maximum Ratings						
Drain-Source Diode Forward Current	I_S				20	A
Drain-Source Diode Forward Voltage ^b	V_{SD}	$V_{GS} = 0V, I_S = 4A$			1.3	V

Notes :

a.Repetitive Rating : Pulse width limited by maximum junction temperature

b.Pulse Test : Pulse Width < 300 μs , Duty Cycle < 2%.

c.Guaranteed by design, not subject to production testing.

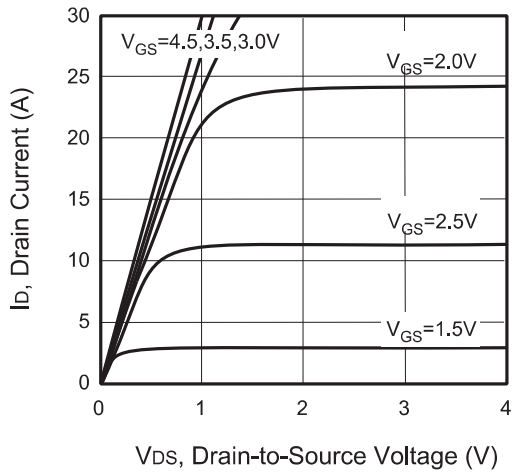


Figure 1. Output Characteristics

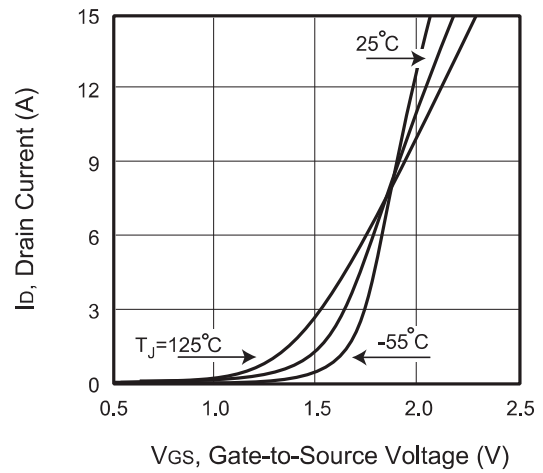


Figure 2. Transfer Characteristics

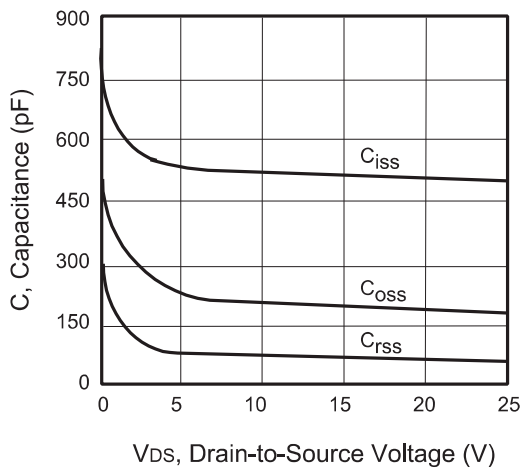


Figure 3. Capacitance

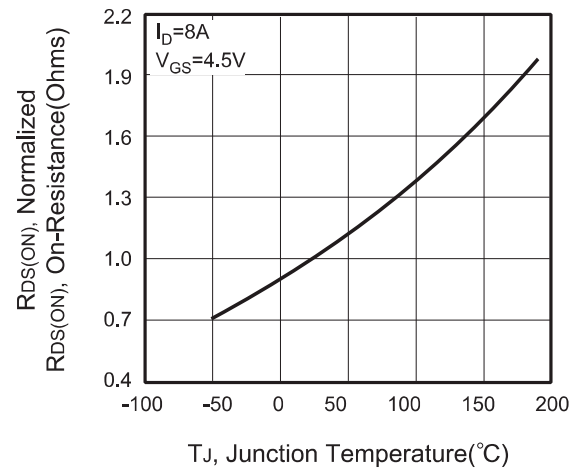


Figure 4. On-Resistance Variation with Temperature

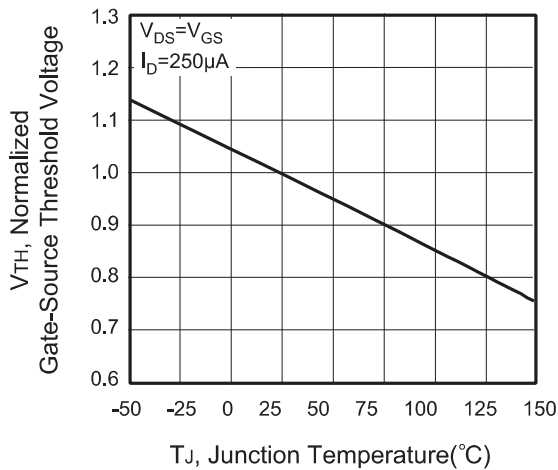


Figure 5. Gate Threshold Variation with Temperature

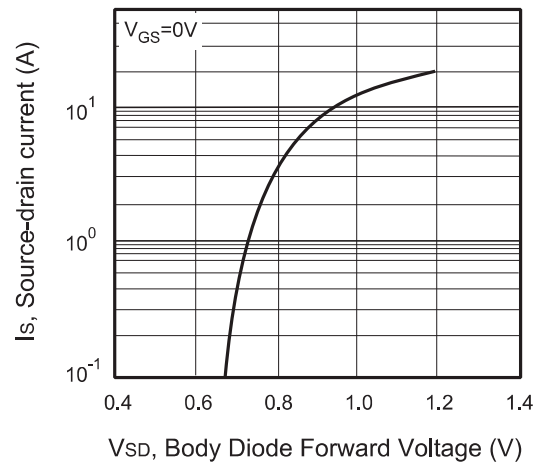


Figure 6. Body Diode Forward Voltage Variation with Source Current

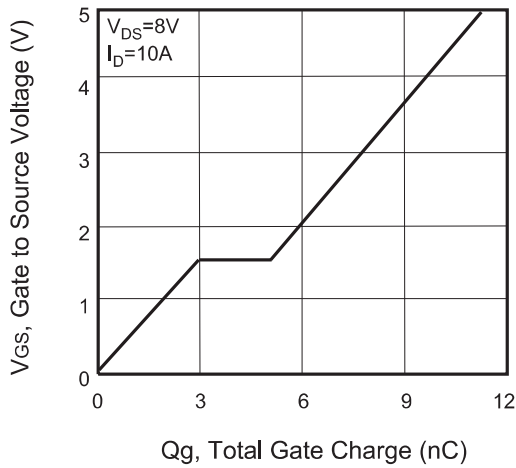


Figure 7. Gate Charge

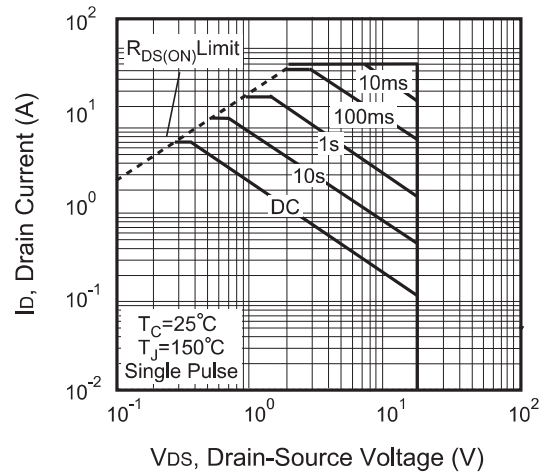


Figure 8. Maximum Safe Operating Area

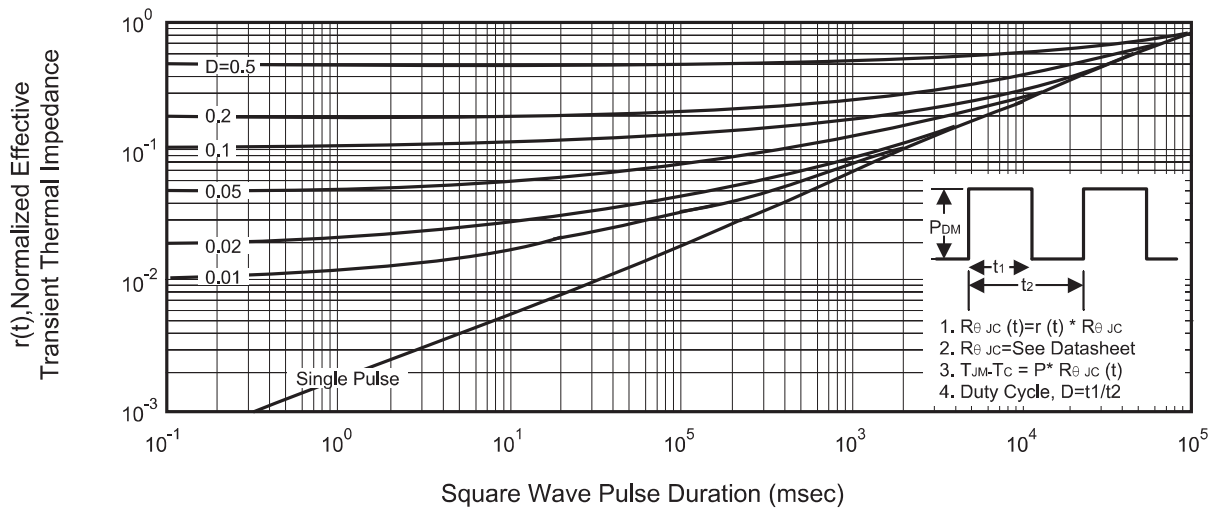
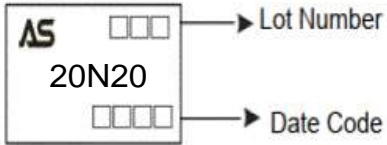


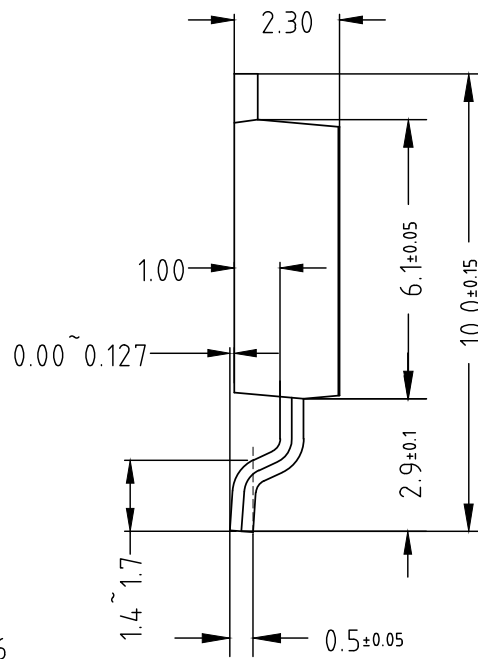
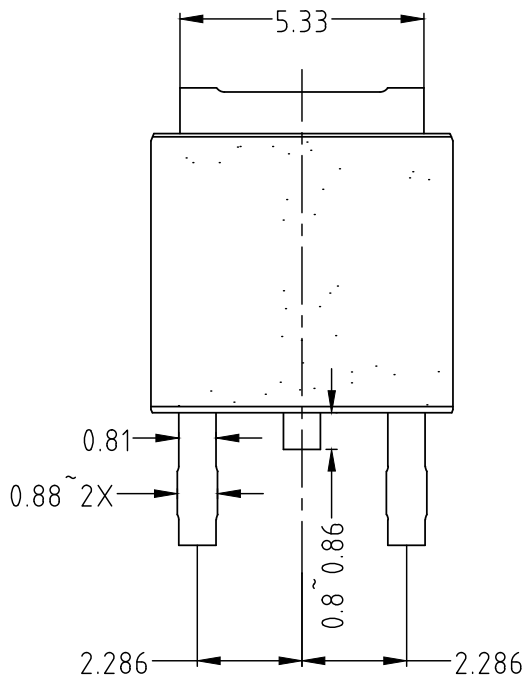
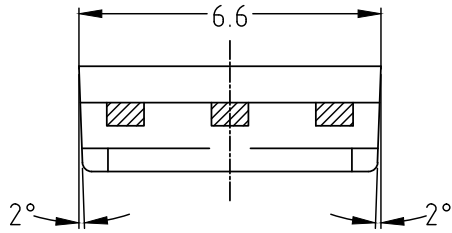
Figure 9 . Normalized Thermal Transient Impedance Curve

Ordering and Marking Information

Ordering Device No.	Marking	Package	Packing	Quantity
ASDM20N20KQ-R	20N20	TO-252	Tape&Reel	2500/Reel

PACKAGE	MARKING
TO-252	 <p>AS □□ → Lot Number 20N20 □□□□ → Date Code</p>

TO-252



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